

MOS FIELD EFFECT TRANSISTOR

3SK252

RF AMPLIFIER FOR CATV TUNER N-CHANNEL SI DUAL GATE MOS FIELD-EFFECT TRANSISTOR 4 PINS MINI MOLD

FEATURES

• Low Vdd Use : (Vds = 3.5 V)

Driving Battery

• Low Noise Figure : NF1 = 2.0 dB TYP. (f = 470 MHz)

NF2 = 0.8 dB TYP. (f = 55 MHz)

• High Power Gain : $G_{PS} = 19.0 \text{ dB TYP.}$ (f = 470 MHz)

• Suitable for use as RF amplifier in CATV tuner.

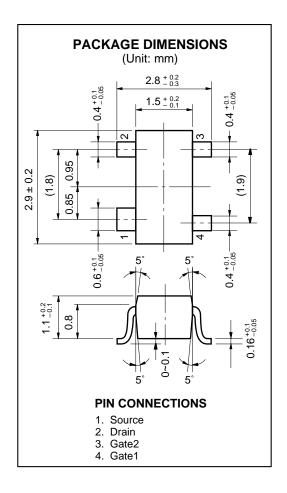
· Automatically Mounting: Embossed Type Taping

Package : 4 Pins Mini Mold

ABSOLUTE MAXIMUM RATINGS (TA = 25 $^{\circ}$ C)

VDSX	18	V
Vg1s	±8*1	V
V _{G2} S	±8*1	V
V_{G1D}	18	V
V_{G2D}	18	V
lο	25	mΑ
Pp	200* 2	mW
Tch	125	°C
Tstg	-55 to +125	°C
	VG1S VG2S VG1D VG2D ID PD Tch	VG1S ±8*1 VG2S ±8*1 VG1D 18 VG2D 18 ID 25 PD 200*2 Tch 125

*1: $RL \ge 10 \text{ k}\Omega$ *2: Free air



PRECAUTION:

Avoid high static voltages or electric fields so that this device would not suffer from any damage due to those voltage or fields.



ELECTRICAL CHARACTERISTICS (TA = 25 $^{\circ}$ C)

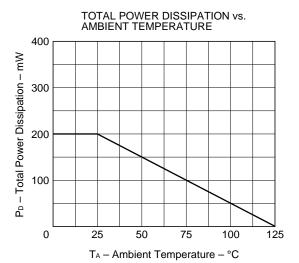
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Drain to Source Breakdown Voltage	BV _{DSX}	18			V	$V_{G1S} = V_{G2S} = -2 \text{ V}, \text{ ID} = 10 \mu\text{A}$	
Drain Current	IDSX	0.1		5.0	mA	V _{DS} = 3.5 V, V _{G2S} = 3 V, V _{G1S} = 0.75 V	
Gate1 to Source Cutoff Voltage	V _{G1S(off)}	-1.0	0	+1.0	V	$V_{DS} = 3.5 \text{ V}, V_{G2S} = 3 \text{ V}, I_{D} = 10 \mu A$	
Gate2 to Source Cutoff Voltage	VG2S(off)	0	0.5	1.0	V	$V_{DS} = 3.5 \text{ V}, V_{G1S} = 3 \text{ V}, I_{D} = 10 \mu A$	
Gate1 Reverse Current	I _{G1SS}			±20	nA	VDS = 0, VG2S = 0, VG1S = ±6 V	
Gate2 Reverse Current	I _{G2SS}			±20	nA	VDS = 0, VG1S = 0, VG2S = ±6 V	
Forward Transfer Admittance	yfs	14	18	23	mS	$V_{DS} = 3.5 \text{ V}, V_{G2S} = 3 \text{ V}, I_{D} = 7 \text{ mA}$ $f = 1 \text{ kHz}$	
Input Capacitance	Ciss	2.4	2.9	3.4	pF	V _{DS} = 3.5 V, V _{G2S} = 3 V, I _D = 7 mA f = 1 MHz	
Output Capacitance	Coss	0.9	1.2	1.5	pF		
Reverse Transfer Capacitance	Crss		0.01	0.03	pF		
Power Gain	Gps	16	19	22	dB	VDS = 3.5 V, VG2S = 3 V, ID = 7 mA	
Noise Figure 1	NF1		2.0	3.0	dB	f = 470 MHz	
Noise Figure 2	NF2		0.8	2.3	dB	$V_{DS} = 3.5 \text{ V}, V_{G2S} = 3 \text{ V}, I_{D} = 7 \text{ mA}$ $f = 55 \text{ MHz}$	

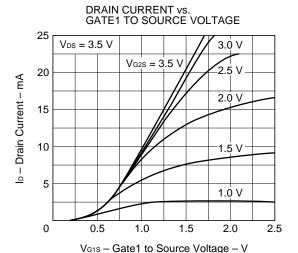
IDSX Classification

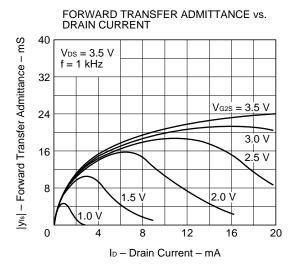
Rank	U1E/UAE*
Marking	U1E
IDSX (mA)	0.1 to 5.0

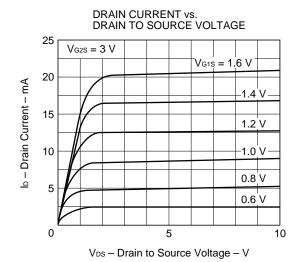
^{*} Old Specification / New Specification

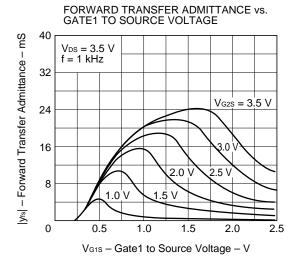
TYPICAL CHARACTERISTICS (TA = 25 °C)

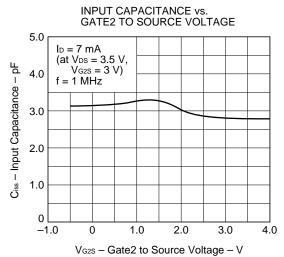




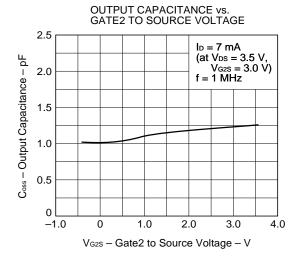


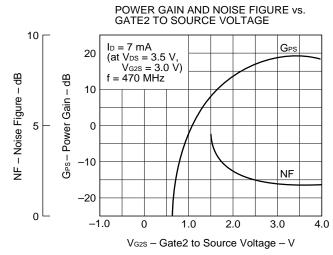






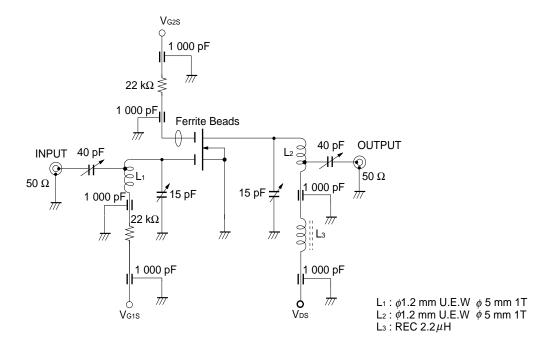




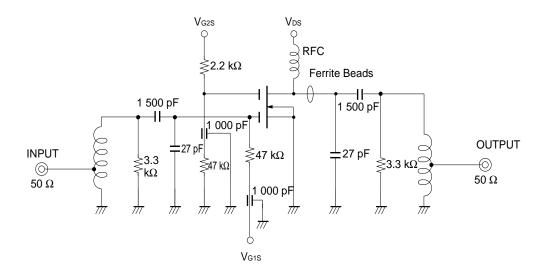




GPS AND NF TEST CIRCUIT AT f = 470 MHz



NF TEST CIRCUIT AT f = 55 MHz



No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in this document.

NEC Corporation does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from use of a device described herein or any other liability arising from use of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Corporation or others.

While NEC Corporation has been making continuous effort to enhance the reliability of its semiconductor devices, the possibility of defects cannot be eliminated entirely. To minimize risks of damage or injury to persons or property arising from a defect in an NEC semiconductor device, customer must incorporate sufficient safety measures in its design, such as redundancy, fire-containment, and anti-failure features.

NEC devices are classified into the following three quality grades:

"Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices in "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact NEC Sales Representative in advance.

Anti-radioactive design is not implemented in this product.

M4 94.11